

CQY80X, CQY80NX
CQY80, CQY80N



ISOCOM
COMPONENTS

**OPTICALLY COUPLED
ISOLATOR
PHOTOTRANSISTOR OUTPUT**



APPROVALS

- UL recognised, File No. E91231
- **'X' SPECIFICATION APPROVALS**
- CQY80X is VDE 0884 in 3 available lead forms :-
 - STD
 - G form
 - SMD approved to CECC 00802
- CQY80NX - VDE 0884 pending
- CQY80X is certified to EN60950 by the following Test Bodies :-
 - Nemko - Certificate No. P96101299
 - Fimko - Registration No. 190469-01..22
 - Semko - Reference No. 9620076 01
 - Demko - Reference No. 305567
- CQY80NX - EN60950 pending

DESCRIPTION

The CQY80 series of optically coupled isolators consist of infrared light emitting diode and NPN silicon photo transistor in a standard 6 pin dual in line plastic package.

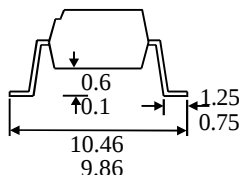
FEATURES

- Options :-
 - 10mm lead spread - add G after part no.
 - Surface mount - add SM after part no.
 - Tape&reel - add SMT&R after part no.
- High Isolation Voltage (5.3kV_{RMS}, 7.5kV_{PK})
- Custom electrical selections available

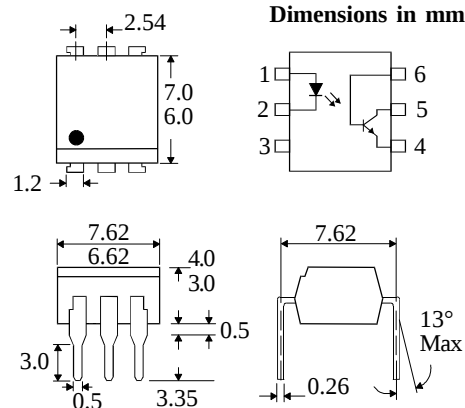
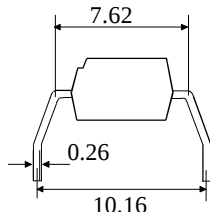
APPLICATIONS

- DC motor controllers
- Industrial systems controllers
- Signal transmission between systems of different potentials and impedances

**OPTION SM
SURFACE MOUNT**



OPTION G



**ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)**

Storage Temperature _____ -55°C to + 150°C
Operating Temperature _____ -55°C to + 100°C
Lead Soldering Temperature
(1/16 inch (1.6mm) from case for 10 secs) 260°C

INPUT DIODE

Forward Current _____ 60mA
Reverse Voltage _____ 6V
Power Dissipation _____ 105mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV_{CEO} _____ 32V
Collector-base Voltage BV_{CBO} _____ 70V
Emitter-collector Voltage BV_{ECO} _____ 6V
Power Dissipation _____ 160mW

POWER DISSIPATION

Total Power Dissipation _____ 200mW
(derate linearly 2.67mW/°C above 25°C)

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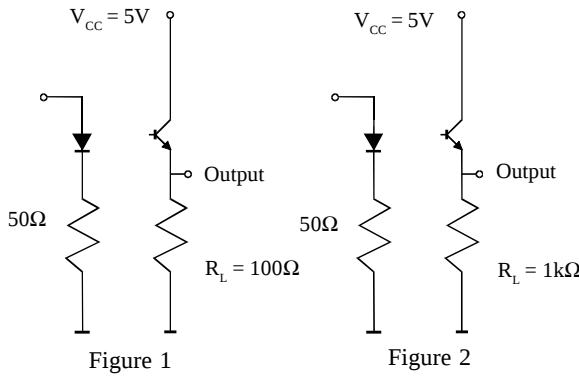
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)	6	1.2	1.60	V	$I_F = 50\text{mA}$ $I_R = 10\mu\text{A}$ $V_R = 6\text{V}$
	Reverse Voltage (V_R)			10	V	
	Reverse Current (I_R)				μA	
Output	Collector-emitter Breakdown (BV_{CEO}) (Note 2)	32		200	V	$I_C = 1\text{mA}$
	Emitter-collector Breakdown (BV_{ECO})	6			V	$I_E = 100\mu\text{A}$
	Collector-emitter Dark Current (I_{CEO})				nA	$V_{CE} = 20\text{V}$
Coupled	I_C / I_F (CTR) (Note 2)	0.5		0.3		$10\text{mA } I_F, 5\text{V } V_{CE}$
	Current Transfer Ratio (CTR) (Note 2)	50			%	$10\text{mA } I_F, 5\text{V } V_{CE}$
	Collector-emitter Saturation Voltage $V_{CE(SAT)}$				V	$10\text{mA } I_F, 1\text{mA } I_C$
	Input to Output Isolation Voltage V_{ISO}	5300 7500			V_{RMS} V_{PK}	See note 1 See note 1
	Input-output Isolation Resistance R_{ISO}	5×10^{10}			Ω	$V_{IO} = 500\text{V}$ (note 1)

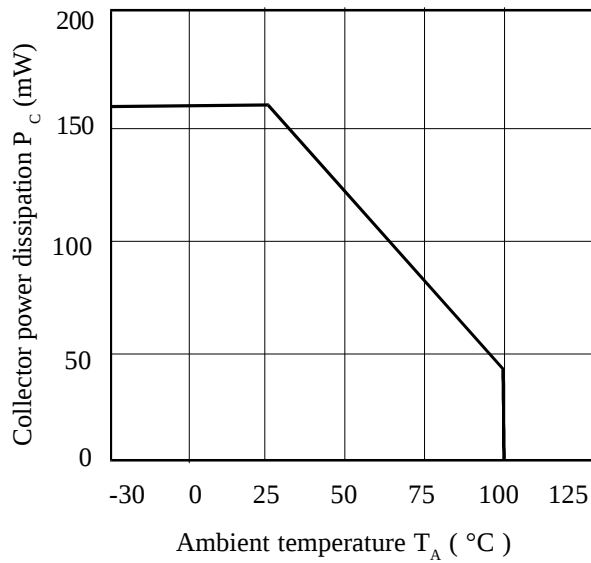
Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

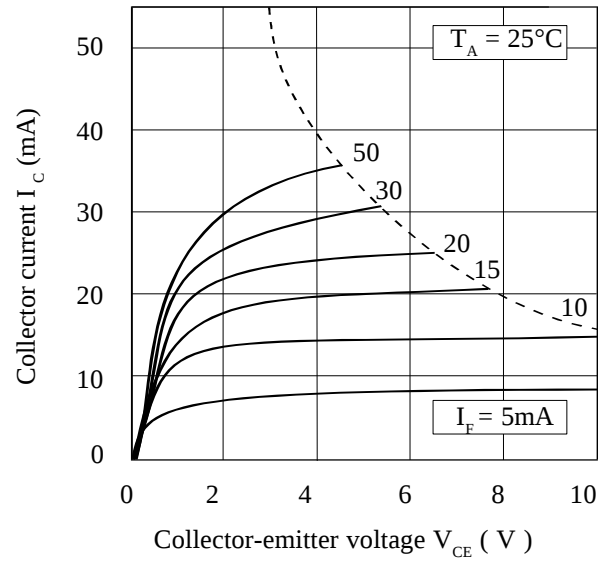
Type	$R_L = 100\Omega$ see fig 1							$R_L = 1\text{k}\Omega$ see fig 2		
	td μs	tr μs	ton μs	ts μs	tf μs	toff μs	I_C mA	ton μs	toff μs	I_F mA
CQY80 CQY80N	4.0	7.0	11.0	0.3	6.7	7.0	5	25.0	42.5	10



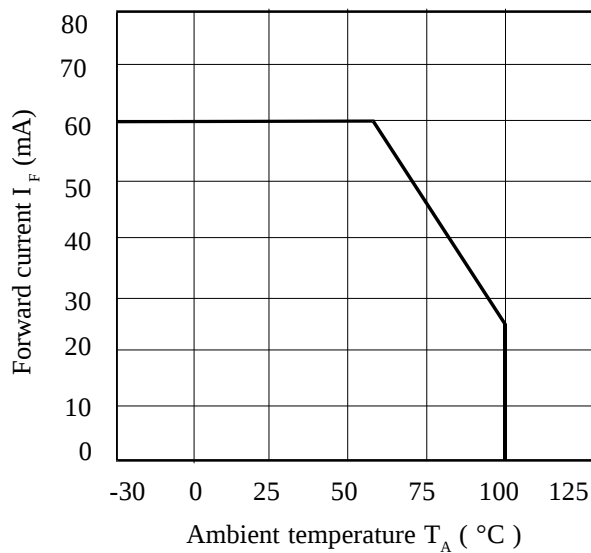
Collector Power Dissipation vs. Ambient Temperature



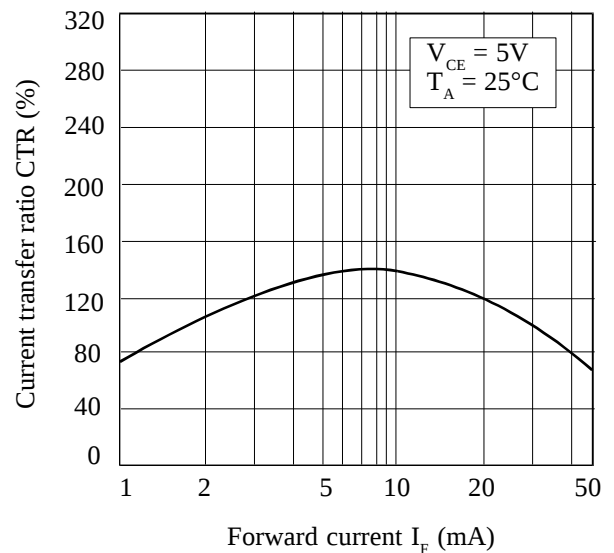
Collector Current vs. Collector-emitter Voltage



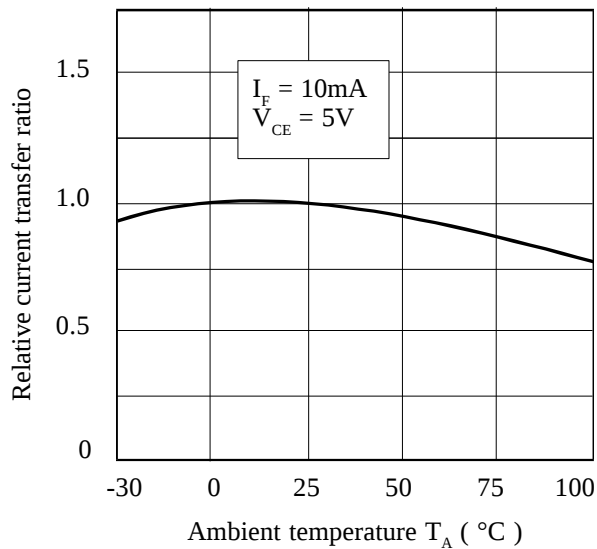
Forward Current vs. Ambient Temperature



Current Transfer Ratio vs. Forward Current



Relative Current Transfer Ratio vs. Ambient Temperature



Collector-emitter Saturation Voltage vs. Ambient Temperature

